

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L20	36	permitivit\$4 near4 (SiO or "SiO.sub.2" or "silicon oxide" or "silicon dioxide" or SiN or "silicon nitride" or SiON or "silicon oxynitride")	USPAT; US-PGP; UB; EPO; JPO; DERWEN; T; IBM_TD; B	2003/10/24 16:36
2	BRS	L21	851	(index near2 refraction) near4 (SiO or "SiO.sub.2" or "silicon oxide" or "silicon dioxide" or SiN or "silicon nitride" or SiON or "silicon oxynitride")	USPAT; US-PGP; UB; EPO; JPO; DERWEN; T; IBM_TD; B	2003/10/24 16:47
3	BRS	L22	2443547	substrate\$3 or wafer\$3 or MOSFET or transistor\$3 or imaging	USPAT; US-PGP; UB; EPO; JPO; DERWEN; T; IBM_TD; B	2003/10/24 16:48
4	BRS	L23	719	21 and 22	USPAT; US-PGP; UB; EPO; JPO; DERWEN; T; IBM_TD; B	2003/10/24 16:48
5	BRS	L24	24202	(len\$3 or microlen\$3 or (micro near2 len\$3)) near4 coat\$8	USPAT; US-PGP; UB; EPO; JPO; DERWEN; T; IBM_TD; B	2003/10/24 16:53

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L25	213	"CMOS pixel"	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/10/24 16:49
7	BRS	L26	44	23 and 24	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/10/24 16:49
8	BRS	L27	9633	24 and 22	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/10/24 16:54
9	BRS	L28	195	27 and CMOS	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/10/24 16:54